	Hits	Search Text	DBs
1	9	hcbt	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
2	11722	horizontal$ near4 current	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
3	69593	bipolar adj2 transistor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
4	27	S2 near4 S3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
5	234	257/557	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
6	11781	horizontal$ near4 current	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
7	69995	bipolar adj2 transistor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
8	27	S6 near4 S7	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
9	980	257/197	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
10	336	257/577	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
11	5	horizontal adj3 current adj3 bipolar adj3 transistor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
12	4	(horizontal adj3 current) near10 (bipolar adj2 transistor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
13	9	S6 and S10	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
14	9	S13 not S11	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB

	Hits	Search Text	DBs
15	144	257/575	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
16	4005	polysilicon near3 spacer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
17	301033	"257"/$.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
18	155	S16 same bipolar	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
19	122	S17 and S18	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB